

# MAGNETO-OPTICAL ABSORPTION COEFFICIENTS OF MONOLAYER MoSe<sub>2</sub>

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**Abstract.** We study the linear, third-order nonlinear, and total absorption coefficients (OACs) caused by intra- and inter-band transitions in monolayer MoSe<sub>2</sub> in the presence of a magnetic field by using the compact density matrix approach. The results show that the OACs display the blue-shift behaviour with an increase in the magnetic field. The Zeeman fields do not affect the peak positions but reduce peak intensities slightly. Besides, the strong spin-orbit coupling in monolayer MoSe<sub>2</sub> causes the peaks to differ significantly due to spin-up and spin-down. The OACs due to intra-band transition display only one peak in the THz range, while the inter-band spectra show a series of peaks in the near-infrared optical range, making monolayer MoSe<sub>2</sub> a promising candidate for novel optoelectronic applications.

**Keywords:** monolayer MoSe<sub>2</sub>, magneto-optical absorption coefficients

## 1 Introduction

Layered materials such as graphene [1], phosphorene [2], silicene [3], germanene [4], and transition-metal dichalcogenides (TMDC) [5, 6] have attracted great interest because of their outstanding properties. These materials are attractive thanks to their fundamental physical properties and great potential applications [7]. With their large natural bandgaps, the TMDCs resolve the gapless problem of graphene, gradually emerging as a potential candidate for new generation materials. That is why the TMDCs have attracted wide attention from scientists in recent years. Among them, monolayer molybdenum diselenide (MoSe<sub>2</sub>) has been studied increasingly due to its extraordinary properties [8]. MoSe<sub>2</sub> has strong spin-orbit-coupling (SOC)

with conduction band spin splitting of 0.184 eV and valence band spin splitting of  $-0.021$  eV [9], which provides an excellent system for spin control [10]. In addition, the bandstructure of MoSe<sub>2</sub> shows a pair of mismatched valleys at points K and K'. The different conductive and valence bands are spaced by a direct bandgap in the infrared region close to the visible spectrum, which results in an efficient electromagnetic wave absorption and emission.

The linear and nonlinear optical properties of two-dimensional layered materials have been investigated widely in recent years due to their importance for understanding the response of semiconductors stimulated by an electromagnetic field in detail [6, 11, 12]. In this work, we study the linear, third-order nonlinear, and total absorption coefficients (OACs) in monolayer

MoSe<sub>2</sub> in a perpendicular magnetic field. We use single-particle eigenfunctions and eigenvalues of this material in the magnetic field. Using the density matrix theory, we calculate the OACs for both intra- and inter-band transitions between the two bands. In Sec. 2, we show the model and the theoretical results. Next, the numerical results and discussion are described in Sec. 3. Finally, we show the conclusion in Sec. 4.

## 2 Theory

### 2.1 Single-particle electronic model

We consider a two-dimensional MoSe<sub>2</sub> system where carriers move freely in the (*xy*) plane, and a uniform static magnetic field *B* is applied to the *z*-direction. The low-energy Hamiltonian is given as follows:

$$H_0 = v_F(\tau\sigma_x\pi_x + \sigma_y\pi_y) + (\Delta_{\tau,s} + d\Delta_z)\sigma_z + P_{\tau,s} + sM_s - \tau M_v, \quad (1)$$

where  $\hbar v_F = 3.11$  (eVÅ) is the Fermi energy [13];  $\sigma_i$  ( $i = x, y, z$ ) are the Pauli matrices;  $\tau = \pm 1$  is the valley index (for K and K');  $s = \pm 1$  is for spin up and spin down;  $2d$  is the distance between the Mo and Se sub-lattices;  $\Delta_z = eE_z$  with  $E_z$  is the electric field applied to the *z*-direction;  $\vec{\pi} = \vec{p} + e\vec{A}$  is the canonical momentum with  $\vec{p}$  and  $\vec{A}$  being the normal momentum and the vector potential. The Dirac mass and the offset energy expressions are [14]

$$\Delta_{\tau,s} = \Delta + s\tau(\lambda_c - \lambda_v) / 4, \quad (2)$$

$$P_{\tau,s} = s\tau(\lambda_c + \lambda_v) / 4. \quad (3)$$

where  $\Delta = 0.74$  eV is the intrinsic band-gap [13]; the Zeeman fields are  $M_i = g_i\mu_B B / 2$ , with  $i = s, v$  corresponding to the spin and valley fields;  $\mu_B$  is the Bohr magneton;  $g_i = 2 + g'_i$  with  $g'_s = 0.29$  and  $g'_v = 3.03$  are the Landé

factors [15]. The corresponding eigenvalues of Eq. (1) are

$$E_\lambda = E_{n,s}^{\tau,p} = pE_{n,s}^\tau + P_{\tau,s} + sM_s - \tau M_v. \quad (4)$$

Here,  $p = \pm 1$  refer to the conduction and valence bands, and

$$E_{n,s}^\tau = \sqrt{n(\hbar\omega_c)^2 + (\Delta_{\tau,s}^z)^2}, n = 0, 1, 2, \dots \quad (5)$$

where  $\Delta_{\tau,s}^z = \Delta_{\tau,s} + d\Delta_z$  and  $\omega_c = v_F\sqrt{2eB/\hbar}$  is the cyclotron frequency. The eigenfunctions are  $|\lambda\rangle = e^{ik_y y} \psi_{n,s}^{\tau,p}(x) / \sqrt{L_y}$ ,

where

$$\psi_{n,s}^{\tau,p}(x) = \begin{pmatrix} \tau A_{n,s}^{\tau,p} \phi_{n-1}(x - x_0) \\ B_{n,s}^{\tau,p} \phi_n(x - x_0) \end{pmatrix}, \quad (6)$$

with  $\phi_n(x)$  being the normalization oscillator functions, and the normalization constants are

$$A_{n,s}^{\tau,p} = \sqrt{\frac{pE_{n,s}^\tau + \Delta_{\tau,s}^z}{2pE_{n,s}^\tau}}, B_{n,s}^{\tau,p} = \sqrt{\frac{pE_{n,s}^\tau - \Delta_{\tau,s}^z}{2pE_{n,s}^\tau}}. \quad (7)$$

In the next subsection, we will use the above equations to evaluate the OACs.

### 2.2 Optical absorption coefficients

Using the compact density matrix approach, we calculate the linear and nonlinear optical susceptibilities for transitions between the two bands  $|\lambda\rangle$  and  $|\lambda'\rangle$  as follows [6]:

$$\varepsilon_0 \chi_{xx}^{(1)}(\Omega) = \frac{1}{2\pi\hbar\alpha_c^2} \sum_{\lambda,\lambda'} \frac{(f_\lambda - f_{\lambda'}) (d_{\lambda',\lambda}^x)^* d_{\lambda,\lambda'}^x}{E_{\lambda',\lambda} - \hbar\Omega - i\hbar\gamma_0} \quad (8)$$

$$\varepsilon_0 \chi_{xx}^{(3)}(\Omega) = -\frac{1}{2\pi\hbar\alpha_c^2} \sum_{\lambda,\lambda'} \frac{(f_\lambda - f_{\lambda'}) (d_{\lambda',\lambda}^x)^* d_{\lambda,\lambda'}^x}{E_{\lambda',\lambda} - \hbar\Omega - i\hbar\gamma_0} \times \left[ \frac{4(d_{\lambda',\lambda}^x)^* d_{\lambda,\lambda'}^x}{(E_{\lambda',\lambda} - \hbar\Omega)^2 + (\hbar\gamma_0)^2} - \frac{(d_{\lambda',\lambda}^x - d_{\lambda\lambda}^x)^2}{(E_{\lambda',\lambda} - i\hbar\gamma)(E_{\lambda,\lambda} - \hbar\Omega - i\hbar\gamma_0)} \right], \quad (9)$$

where  $h$  (3.35 Å) is the thickness of the MoSe<sub>2</sub> monolayer [16];  $\alpha_c$  is the magnetic length;  $d_{\lambda'\lambda}^x = -e\delta_{k_y, k_y'} \langle \psi_{n',s'}^{r,p'} | x | \psi_{n,s}^{r,p} \rangle$  is the dipole matrix element in the  $x$ -direction,  $E_{\lambda',\lambda} = E_{\lambda'} - E_{\lambda}$ ,  $\hbar\gamma_0 = 0.2\sqrt{B}$  (meV) [6];  $\hbar\Omega$  is the photon energy. From the expressions for the optical susceptibilities shown in Eqs. (8) and (9), we can find the OACs as follows [17]:

$$\alpha(\Omega, I) = \alpha^{(1)}(\Omega) + \alpha^{(3)}(\Omega, I), \quad (10)$$

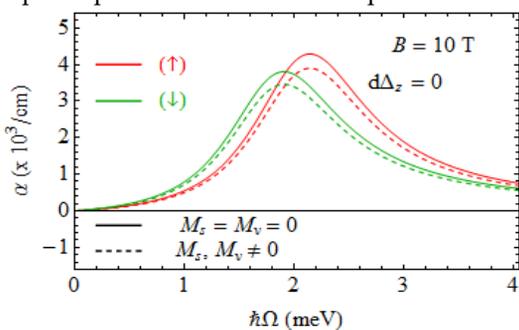
$$\alpha^{(k)}(\Omega, I) = \Omega \sqrt{\frac{\mu}{\varepsilon_R}} \text{Im}[\varepsilon_0 \chi_{xx}^{(k)}(\Omega)]. \quad (11)$$

here,  $k=1,3$  for the linear and nonlinear terms;  $\mu$  is the permeability of the material;  $\varepsilon_R = n_r^2 \varepsilon_0$  with  $\varepsilon_0$  being the permittivity of vacuum;  $n_r$  (4.25) is the refractive index;  $I$  ( $3 \times 10^6$  W/m<sup>2</sup>) is the light intensity.

### 3 Results and discussion

This section provides details for numerical evaluating the linear, nonlinear, and total OACs in monolayer MoSe<sub>2</sub>. The parameters are shown as they appear.

In Fig. 1, we show the linear OACs caused by the intra-band transition as a function of photon energy, including the effect of the spin and valley Zeeman fields. We can see only one absorption peak for each case of spin. This result



**Fig. 1.** Linear OAC for intra-band transition versus photon energy when  $B = 10$  T and  $d\Delta_z = 0$  for spin-up and spin-down cases

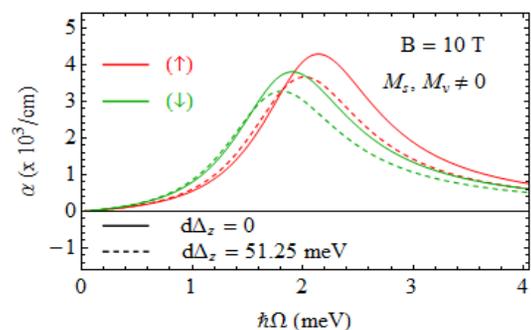
is in good agreement with that obtained in monolayer MoS<sub>2</sub> [12], WS<sub>2</sub> [6], and phosphorene [11]. Since the SOC in monolayer MoSe<sub>2</sub> is strong, the peak positions due to spin-up and spin-down are separated clearly with slightly higher energy for the spin-up case. Besides, the Zeeman field effect does not change the peak positions but reduces the peak intensities. This behaviour is consistent with that obtained in monolayer WS<sub>2</sub> [6].

In Fig. 2, we show the effect of the electric field on the linear OAC due to intra-band transitions. When the electric field increases, the peak positions shift to the lower-energy region, and the peak intensities decrease. This behaviour might result from the absorbed photon energy caused by the intra-band transition as follows:

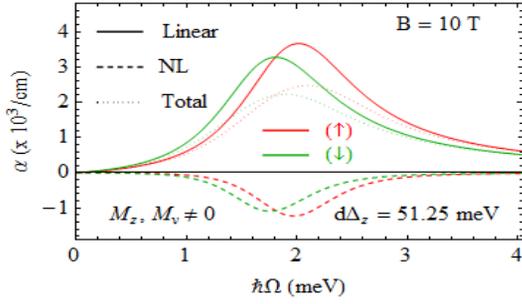
$$\hbar\Omega_{\text{int ra}} = \frac{(\hbar\omega_c)^2}{2\Delta_{\tau,s}^z} = \frac{(\hbar\omega_c)^2}{2(\Delta_{\tau,s} + d\Delta_z)}. \quad (12)$$

It is clear from Eq. (12) that  $\hbar\Omega_{\text{int ra}}$  decreases with the increase in the electric field.

Fig. 3 shows the dependence of the linear, third-order nonlinear, and total OACs for intra-band transitions on the photon energy for the spin-up case when  $B = 10$  T,  $d\Delta_z = 51.25$  meV, and  $M_s$  and  $M_v \neq 0$ . Since the third-order nonlinear OAC has a negative value, the total OAC decreases, and this change agrees with what was reported in previous works [6, 11, 12].

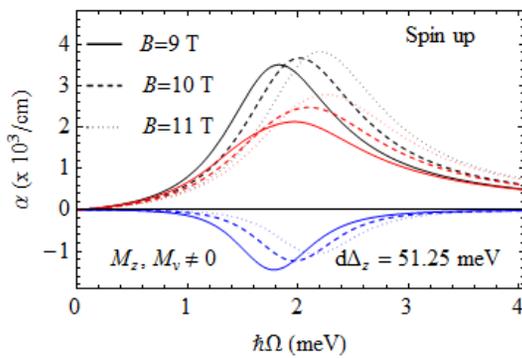


**Fig. 2.** Linear OAC for intra-band transition versus photon energy when  $B = 10$  T and  $M_s$  and  $M_v \neq 0$  for two values of the electric field



**Fig. 3.** Linear, third-order nonlinear, and total OACs for intra-band transition versus photon energy when  $B = 10$  T,  $d\Delta_z = 51.25$  meV, and  $M_s$  and  $M_v \neq 0$

Since the behaviour of the OACs for spin-up and spin-down cases is the same, in the following, we only evaluate for the spin-up case but the results could be also validated for spin-down one. In Fig. 4, we show the dependence of the linear, third-order nonlinear, and total OACs for intra-band transition versus photon energy for different values of  $B$ . It is seen that when the magnetic field increases, the peak positions shift to the higher region of energy. This shift results from the rise in cyclotron energy with the increase in the magnetic field. However, the magnetic field affects the peak intensities of the linear and third-order nonlinear OACs oppositely. While the intensities of the linear OAC increase with the magnetic field, those of the third-order nonlinear

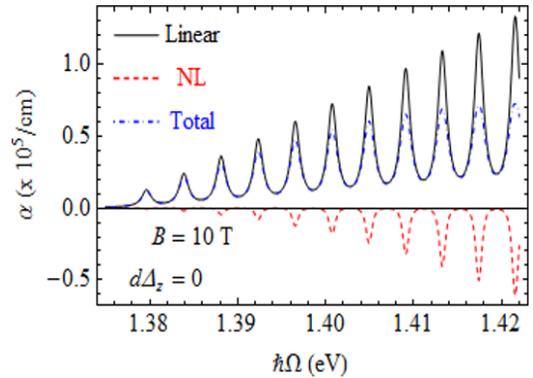


**Fig. 4.** Linear, third-order nonlinear, and total OACs for intra-band transition versus photon energy for different values of  $B$ . The results are calculated for the spin-up case when  $d\Delta_z = 51.25$  meV, and  $M_s$  and  $M_v \neq 0$ .

OAC decrease. Since the reduction of the peak intensities of the third-order nonlinear OAC is smaller than the increase of the linear OAC, the total OAC increases when the magnetic field increases. This result agrees well with that of monolayer phosphorene [11],  $WS_2$  [6], and conventional low-dimensional structure [18].

We now turn our attention to study the OACs due to inter-band transition. Fig. 5 shows the linear, third-order nonlinear, and total OACs dependence on the photon energy. The calculations are presented for the spin-up case at a particular value of  $d\Delta_z$  and when  $M_s$  and  $M_v \neq 0$ . Unlike in the intra-band transition cases where only one peak at the THz region appear in the absorption spectra, a series of peaks appear in the absorption spectra at the near-infrared region due to inter-band transition. This appearance might result from the expression of the absorbed photon energy as follows:

$$\hbar\Omega_{inter} = \frac{(2n+1)(\hbar\omega_c)^2}{2(\Delta_{\tau,s} + d\Delta_z)} + 2(\Delta_{\tau,s} + d\Delta_z). \quad (13)$$



**Fig. 5.** Linear, third-order nonlinear, and total OACs for inter-band transition versus photon energy. The results are calculated for the spin-up case when  $B = 10$  T,  $d\Delta_z = 0$ , and  $M_s$  and  $M_v \neq 0$ .

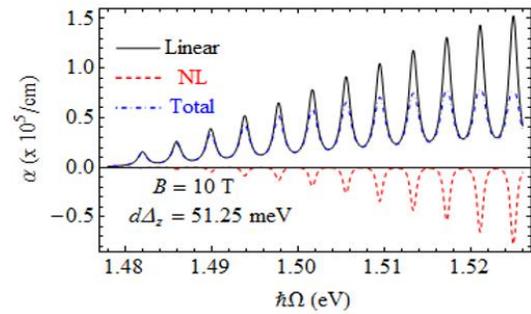
It is clear that  $\hbar\Omega_{inter}$  is proportional to  $(2n + 1)$ , leading to the overlapped behaviour of the resonant peaks but gradually shifts to the higher-energy region with the increase of the Landau levels. That is the reason why the absorbed spectra appear in a series of peaks. For the peak positions, we see that  $\hbar\Omega_{inter} \propto 2\Delta_{\tau,s}$ , whose value is at the near-infrared region. Besides, the peak intensities due to the inter-band transitions are much higher than those due to intra-band transitions. These results also agree well with those obtained in the monolayer WS<sub>2</sub> [6] and MoS<sub>2</sub> [12].

Like Fig. 5, Fig. 6 shows the OACs when  $d\Delta_z = 51.25$  meV. When the electric field is taken into account, the absorption spectra system shifts to the higher-energy region. This can be seen clearly from Eq. (13), which shows the absorbed photon energy is proportional to the electric field.

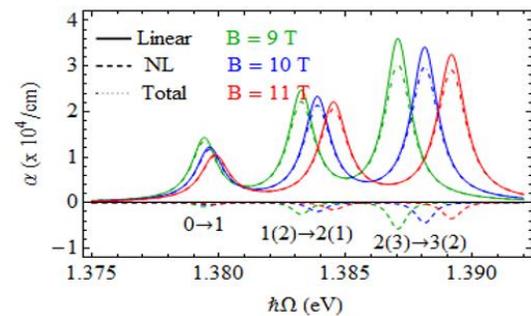
The influence of the magnetic field on the OACs due to inter-band transition is shown in Fig. 7. We can see that the peak positions shift to the higher-energy region because the cyclotron energy increases with the magnetic field. This result is consistent with that reported in the monolayer WS<sub>2</sub> [6] and MoS<sub>2</sub> [12].

## 4 Conclusion

We have studied the linear, third-order nonlinear, and total OACs in the monolayer MoSe<sub>2</sub> in the presence of a perpendicular magnetic field. The results are also calculated when the electric and the Zeeman fields are taken into account. Our results show that the absorption spectrum appears in two different regions depending on the intra-band or inter-band transitions. While the OACs due to the intra-band transition have only one peak at the THz region, the OACs due to the inter-band transition possess a series of peaks at the near-infrared region. Furthermore, the effect



**Fig. 6.** The linear, third-order nonlinear, and total OACs for inter-band transition versus photon. The results are calculated for the spin-up case when  $B = 10$  T,  $d\Delta_z = 51.25$  meV, and  $M_s$  and  $M_v \neq 0$ .



**Fig. 7.** Linear, third-order nonlinear, and total OACs for inter-band transition versus photon for different values of  $B$ . The results are calculated for the spin-up case when  $d\Delta_z = 0$  and  $M_s$  and  $M_v \neq 0$ .

of the Zeeman field and the electric field on the OACs is different: while the Zeeman field does not change the peak positions, the electric field shifts the peak positions due to the intra/inter-band transition to the lower/higher-energy region. Besides, strong SOC in the monolayer MoSe<sub>2</sub> causes the absorption peaks due to the spin-up and the spin-down to separate. Our theoretical results provide the potential of MoSe<sub>2</sub> as a promising material for designing nano-electronic and optical devices.

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